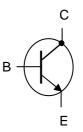


# BSX45-BSX46-BSX47

# NPN MEDIUM POWER TRANSISTORS

The BSX45-BSX46-BSX47 are NPN transistors mounted in TO-39 metal package. They are intended for use in general industrial applications. High current and low voltage. Compliance to RoHS.



## ABSOLUTE MAXIMUM RATINGS

Symbol	Ratings			Value			
Symbol			BSX45	BSX46	BSX47	Unit	
V <sub>CEO</sub>	Collector-Emitter Voltage	I <sub>B</sub> =0	40	60	80	V	
V <sub>CBO</sub>	Collector-Base Voltage	I <sub>E</sub> =0	80	100	120	V	
V <sub>EBO</sub>	Emitter-Base Voltage I <sub>C</sub> =0			7			
I <sub>C</sub>	Collector Current			1			
I <sub>CM</sub>	Collector Peak Current			1.5			
I <sub>BM</sub>	Base Peak Current			200			
P <sub>D</sub>	Total Power Dissipation $T_{amb} = 25^{\circ}$		6.25			W	
TJ	Junction Temperature			200			
T <sub>amb</sub>	Operating ambient temperature			-65 to +150			
T <sub>Stg</sub>	Storage Temperature rang	е	-65 to +150		]		

## **THERMAL CHARACTERISTICS**

Symbol	Ratings	Value	Unit
R <sub>thJ-a</sub>	Thermal Resistance, Junction to ambient	200	°C/W
R <sub>thJ-c</sub>	Thermal Resistance, Junction to case	28	°C/W

### SWITCHING TIMES

Symbol	Ratings		Value	Unit
t <sub>on</sub>	Turn-on time	$I_{Con} = 100 \text{mA}; I_{Bon} = 5 \text{ mA}$	200	ns
t <sub>off</sub>	Turn-off time	I <sub>Boff</sub> = -5 mA	850	ns



## BSX45-BSX46-BSX47 ELECTRICAL CHARACTERISTICS

Tj=25°C unless otherwise specified

Symbol	Ratings	Test Condit	ion(s)	Min	Тур	Max	Unit
		$V_{CB} = 60 \text{ V}, I_{E} = 0$	BSX45 BSX46			30	nA
	Collector Cutoff Current	$V_{CB} = 80 \text{ V}, I_{E} = 0$	BSX47			00	
Сво		$V_{CB} = 60 \text{ V}, \text{ I}_{E} = 0$	BSX45			10	μΑ
		T <sub>j</sub> = 150°C	BSX46		_		
		V <sub>CB</sub> = 80 V, I <sub>E</sub> =0 T <sub>i</sub> = 150°C	BSX47				
<b>I</b> EBO	Emitter Cutoff Current	$V_{BE} = 5.0 \text{ V}, I_{C} = 0$	-	-	-	10	nA
V <sub>CE(SAT)</sub>	Collector-Emitter	$I_{\rm C} = 1 \text{ A}, I_{\rm B} = 100$ mA	BSX45 BSX46		-	1	V
♥ CE(SAT)	saturation Voltage	I <sub>C</sub> = 500 mA I <sub>B</sub> = 25 mA	BSX47	-	-	0.9	v
		$I_{C} = 100 \text{ mA}, V_{CE} = 100 \text{ mA}$				1	
V <sub>BE</sub>	Base-Emitter Voltage	$I_{\rm C} = 500 \text{ mA}, V_{\rm CE} = 100 \text{ mA}$	1 V	0.75	-	1.5	V
		$I_{C} = 1 \text{ A}, V_{CE} = 1 \text{ V}$		-	-	2	
	DC Current Gain		BSX45/10	15	45 40		-
		I <sub>C</sub> = 100 μA	BSX46/10 BSX47/10	15	40	-	
		$V_{CE} = 1 V$	BSX47/10 BSX45/16		90		
			BSX46/16	25		-	
			BSX45/10		63 100 160		
			BSX46/10	63		160	
		I <sub>C</sub> = 100 mA	BSX47/10				
		$V_{CE} = 1 V$	BSX45/16	16			
т.			BSX46/16		160	250	_
h <sub>FE</sub>			BSX47/16				
			BSX45/10		25 40		
		L = 500  m	BSX46/10	25		-	
		I <sub>C</sub> = 500 mA V <sub>CE</sub> = 1 V	BSX47/10				
		VCE - IV	BSX45/16	35	60		
			BSX46/16	35		-	
			BSX45/10				
			BSX46/10	-	20	-	
		$I_{C} = 1 \text{ A}, V_{CE} = 1 \text{ V}$	BSX47/10		- 30 -		
			BSX45/16			-	
		$l_{a} = 50 \text{ m} \text{ M} \text{ M}_{a} = -1$	BSX46/16				
f <sub>T</sub>	Transition frequency	$I_{C} = 50 \text{ mA}, V_{CE} = 10 \text{ V}$ f = 100MHz		50	-	-	MHz
F	Noise figure	$I_{C} = 100 \ \mu A, V_{CE} = 5$ f = 1kHz, B =200Hz		-	3.5	-	db

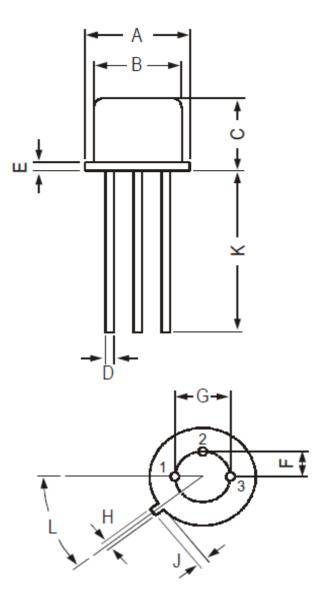


## BSX45-BSX46-BSX47

### **MECHANICAL DATA CASE TO-39**

DIMENSIONS (mm)			
	min	max	
А	8.50	9.39	
В	7.74	8.50	
С	6.09	6.60	
D	0.40	0.53	
E	-	0.88	
F	2.41	2.66	
G	4.82	5.33	
Н	0.71	0.86	
J	0.73	1.02	
K	12.70	-	
L	42°	48°	

Pin 1 :	Emitter
Pin 2 :	Base
Pin 3 :	Collector
Case :	Collector



### **Revised August 2012**

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